

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|---------|---|---|------------------|---------|------------------|
| L1 | 3007090 | memory or storage | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:19 |
| L2 | 1 | 1 and capacitor with (nrom or nitride adj read adj only) adj3 transistor | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:38 |
| L3 | 8 | 1 and capacitor with (nrom or nitride adj read adj only) | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:29 |
| L4 | 2 | ("6440798").PN. | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | OFF | 2005/01/17 16:29 |
| L5 | 44 | 1 and capacitor with (nrom or nitride) adj5 transistor | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:32 |
| L6 | 22 | 5 and (word or wordline) | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:32 |
| L7 | 357 | 1 and capacitor with (nonvolatile or non-volatile or floating adj gate) adj3 transistor | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:39 |
| L9 | 86 | 7 and (dynamic or dram) and (read adj only or \$3rom) | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:41 |
| L10 | 40 | 9 and (nitride or nrom) | US-PGPUB; USPAT; EPO; JPO; DERWENT | OR | ON | 2005/01/17 16:42 |